

DS90LV011AQ Automotive LVDS Differential Driver

Check for Samples: DS90LV011AQ

FEATURES

- AECQ-100 Grade 1
- Conforms to TIA/EIA-644-A Standard
- >400Mbps (200MHz) Switching Rates
- 700 ps (100 ps typical) Maximum Differential Skew
- 1.5 ns Maximum Propagation Delay
- Single 3.3V Power Supply
- ±350 mV Differential Signaling
- Power Off Protection (Outputs in TRI-STATE)
- Pinout Simplifies PCB Layout
- Low Power Dissipation (23 mW @ 3.3V Typical)
- SOT-23 5-Lead Package
- Pin Compatible with SN65LVDS1

DESCRIPTION

The DS90LV011AQ is an LVDS driver optimized for high data rate and low power applications. The DS90LV011AQ is a current mode driver allowing power dissipation to remain low even at high frequency. In addition, the short circuit fault current is also minimized. The device is designed to support data rates in excess of 400Mbps (200MHz) utilizing Low Voltage Differential Signaling (LVDS) technology.

The device is offered in a 5-lead SOT-23 package. The LVDS outputs have been arranged for easy PCB layout. The differential driver outputs provide low EMI with its typical low output swing of 350 mV. The DS90LV011AQ can be paired with its companion single line receiver, the DS90LT012AQ, or with any of TI's LVDS receivers, to provide a high-speed LVDS interface.

Connection Diagram

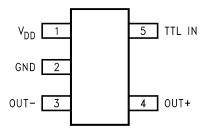
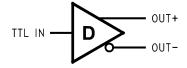


Figure 1. Top View See Package Number MF05A

Functional Diagram



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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

Absolute Maximum Ratings (1)(2)

Absolute maximum rutings	
Supply Voltage (V _{DD})	-0.3V to 4.0V
LVCMOS input voltage (TTL IN)	$-0.3V$ to to $(V_{DD} + 0.3V)$
LVDS output voltage (OUT±)	-0.3V to +3.9V
LVDS output short circuit current	24mA
Maximum Package Power Dissipation @ +25°C	
DBV Package	794 mW
Derate DBV Package	7.22 mW/°C above +25°C
Package Thermal Resistance (4-Layer, 2 oz. Cu, JEDEC)	
θ_{JA}	138.5°C/Watt
θ_{JC}	107.0°C/Watt
Storage Temperature	−65°C to +150°C
Lead Temperature Range Soldering	
(4 sec.)	+260°C
Maximum Junction Temperature	+135°C
ESD Ratings	
HBM ⁽³⁾	≥ 8kV
MM ⁽⁴⁾	≥ 250V
CDM ⁽⁵⁾	≥ 1250V

- (1) Absolute Maximum Ratings are those values beyond which the safety of the device cannot be ensured. They are not meant to imply that the devices should be operated at these limits. Electrical Characteristics specifies conditions of device operation.
- (2) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/Distributors for availability and specifications.
- (3) Human Body Model, applicable std. JESD22-A114C
- (4) Machine Model, applicable std. JESD22-A115-A
- (5) Field Induced Charge Device Model, applicable std. JESD22-C101-C

Recommended Operating Conditions

	Min	Тур	Max	Units
Supply Voltage (V _{DD})	3.0	3.3	3.6	V
Temperature (T _A)	-40	+25	+125	°C

Electrical Characteristics

Over Supply Voltage and Operating Temperature ranges, unless otherwise specified. (1)(2)(3)

Symbol	Parameter	Conditions	Pin	Min	Тур	Max	Units
V _{OD}	Output Differential Voltage	$R_L = 100\Omega$	OUT+,	250	350	450	mV
ΔV_{OD}	V _{OD} Magnitude Change	(Figure 2 and Figure 3)	OUT-		3	35	mV
Vos	Offset Voltage	$R_L = 100\Omega$		1.125	1.22	1.375	V
ΔV _{OS}	Offset Magnitude Change	(Figure 2)		0	1	25	mV
I _{OFF}	Power-off Leakage	$V_{OUT} = 3.6V$ or GND, $V_{DD} = 0V$			±1	±10	μΑ
Ios	Output Short Circuit Current (4)	V_{OUT+} and $V_{OUT-} = 0V$			-6	-24	mA
I _{OSD}	Differential Output Short Circuit Current (4)	V _{OD} = 0V			-5	-12	mA
C _{OUT}	Output Capacitance				3		pF

(1) Current into device pins is defined as positive. Current out of device pins is defined as negative. All voltages are referenced to ground except Von

Product Folder Links: DS90LV011AQ

- (2) All typicals are given for: $V_{DD} = +3.3V$ and $T_A = +25$ °C.
- 3) The DS90LV011AQ is a current mode device and only function with datasheet specification when a resistive load is applied to the drivers outputs.
- (4) Output short circuit current (Ios) is specified as magnitude only, minus sign indicates direction only.

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Electrical Characteristics (continued)

Over Supply Voltage and Operating Temperature ranges, unless otherwise specified. (1)(2)(3)

Symbol	Parameter		Conditions		Min	Тур	Max	Units
V _{IH}	Input High Voltage			TTL IN	2.0		V_{DD}	V
V _{IL}	Input Low Voltage				GND		0.8	V
I _{IH}	Input High Current	$V_{IN} = 3.3V \text{ or } 2$	2.4V			±2	±10	μΑ
I _{IL}	Input Low Current	V _{IN} = GND or	V _{IN} = GND or 0.5V			±1	±10	μΑ
V_{CL}	Input Clamp Voltage	I _{CL} = −18 mA			− 1.5	-0.6		V
C _{IN}	Input Capacitance					3		pF
I _{DD}	Power Supply Current	No Load	No Load $V_{IN} = V_{DD}$ or GND			5	8	mA
		$R_L = 100\Omega$				7	10	mA

Switching Characteristics

Over Supply Voltage and Operating Temperature Ranges, unless otherwise specified. (1)(2)(3)(4)

Symbol	Parameter	Conditions	Min	Тур	Max	Units
t _{PHLD}	Differential Propagation Delay High to Low	$R_L = 100\Omega, C_L = 15 pF$	0.3	1.0	1.5	ns
t _{PLHD}	Differential Propagation Delay Low to High	(Figure 4 and Figure 5)	0.3	1.1	1.5	ns
t _{SKD1}	Differential Pulse Skew t _{PHLD} - t _{PLHD} (5)		0	0.1	0.7	ns
t _{SKD3}	Differential Part to Part Skew (6)		0	0.2	1.0	ns
t _{SKD4}	Differential Part to Part Skew (7)		0	0.4	1.2	ns
t _{TLH}	Transition Low to High Time		0.2	0.5	1.0	ns
t _{THL}	Transition High to Low Time		0.2	0.5	1.0	ns
f _{MAX}	Maximum Operating Frequency (8)			250		MHz

- (1) All typicals are given for: $V_{DD} = +3.3V$ and $T_A = +25$ °C.
- These parameters are ensured by design. The limits are based on statistical analysis of the device performance over PVT (process, voltage, temperature) ranges.
- C_L includes probe and fixture capacitance.

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- Generator waveform for all tests unless otherwise specified: f = 1 MHz, $Z_0 = 50\Omega$, $t_f \le 1$ ns, $t_f \le 1$ ns (10%-90%).
- t_{SKD1}, |t_{PHLD} t_{PLHD}|, is the magnitude difference in differential propagation delay time between the positive going edge and the negative going edge of the same channel.
- t_{SKD3}, Differential Part to Part Skew, is defined as the difference between the minimum and maximum specified differential propagation delays. This specification applies to devices at the same V_{DD} and within 5°C of each other within the operating temperature range.
- (7) t_{SKD4}, part to part skew, is the differential channel to channel skew of any event between devices. This specification applies to devices over recommended operating temperature and voltage ranges, and across process distribution. t_{SKD4} is defined as |Max - Min| differential propagation delay.
- f_{MAX} generator input conditions: $t_r = t_f < 1$ ns (0% to 100%), 50% duty cycle, 0V to 3V. Output criteria: duty cycle = 45%/55%, $V_{OD} > 1$ 250mV.

Parameter Measurement Information

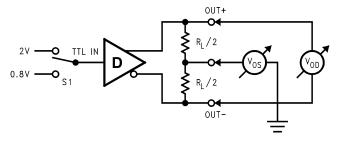


Figure 2. Differential Driver DC Test Circuit



Parameter Measurement Information (continued)

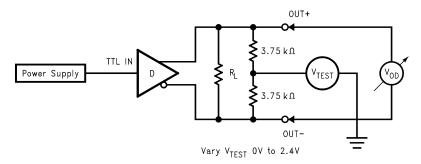


Figure 3. Differential Driver Full Load DC Test Circuit

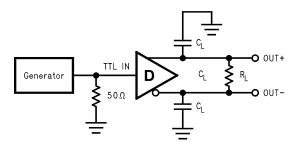


Figure 4. Differential Driver Propagation Delay and Transition Time Test Circuit

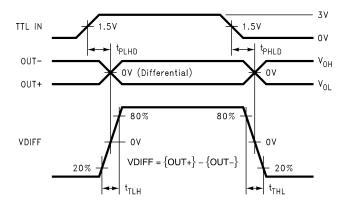


Figure 5. Differential Driver Propagation Delay and Transition Time Waveforms

APPLICATION INFORMATION

DEVICE PIN DESCRIPTIONS

Package Pin Number	Pin Name	Description				
SOT-23	FIII Name	Description				
5	TTL IN	LVTTL/LVCMOS driver input pins				
4	OUT+	Non-inverting driver output pin				
3	OUT-	Inverting driver output pin				
2	GND	Ground pin				
1	V_{DD}	Power supply pin, +3.3V ± 0.3V				

Product Folder Links: DS90LV011AQ





REVISION HISTORY

Changes from Revision C (April 2013) to Revision D						
•	Changed layout of National Data Sheet to TI format	4				

Product Folder Links: DS90LV011AQ



PACKAGE OPTION ADDENDUM

10-Dec-2020

PACKAGING INFORMATION

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Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
							(6)				
DS90LV011AQMF/NOPB	ACTIVE	SOT-23	DBV	5	1000	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	N01Q	Samples
DS90LV011AQMFE/NOPB	ACTIVE	SOT-23	DBV	5	250	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	N01Q	Samples
DS90LV011AQMFX/NOPB	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	N01Q	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

10-Dec-2020

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





Α0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

All difficulties are norminal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
DS90LV011AQMF/NOPB	SOT-23	DBV	5	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
DS90LV011AQMFE/NOP B	SOT-23	DBV	5	250	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
DS90LV011AQMFX/NOP B	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3

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*All dimensions are nominal

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Device Package Type		Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
DS90LV011AQMF/NOPB	SOT-23	DBV	5	1000	210.0	185.0	35.0
DS90LV011AQMFE/NOPB	SOT-23	DBV	5	250	210.0	185.0	35.0
DS90LV011AQMFX/NOPB	SOT-23	DBV	5	3000	210.0	185.0	35.0



SMALL OUTLINE TRANSISTOR



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 2. This drawing is subject to change without notice.
 3. Refernce JEDEC MO-178.

- 4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
- 5. Support pin may differ or may not be present.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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